## NSN 5961-00-487-8790

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-487-8790 **Inclosure Material:** Metal **Overall Length:** 0.673 inches **Overall Diameter:** 0.614 inches **End Application:** An/fps-124 unattending radar (uar). **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 1.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 repetitive peak reverse voltage, peak total value, gate terminal open-circuited **Current Rating Per Characteristic:** 30.00 amperes drain current horsepower metric **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius case **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No